NSN 5961-00-901-3863

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View Online at https://aerobasegroup.com/nsn/5961-00-901-3863

Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.370 inches

Function For Which Designed:

Amplifier

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

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Npn
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Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc and 100.0 collector-to-emitter, resistance between base and emitter

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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